NSN 5961-01-359-2017

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-359-2017 **Inclosure Material:** Glass **Overall Length:** 0.160 inches **Terminal Length:** 0.500 inches **Overall Diameter:** 0.075 inches Joint Electronic Device Engineering Council/jedec/case Outline Designation: Do-35 **Mounting Method: Terminal Features Provided:** Electrostatic sensitive **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 20.0 regulator voltage **Voltage Tolerance In Percent:** -5.0/+5.0 **Current Rating Per Characteristic:** 6.20 milliamperes all primaries horsepower metric **Power Rating Per Characteristic:** 400.0 milliwatts small-signal input power, common-collector preset **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: A110a0